

## 問題 2

MOS トランジスタは非線形特性があるため、動作の解析が困難である。そこで、バイアス点の近傍の微小範囲で解析を行う。この手法を小信号解析と呼ぶ。短チャネル MOS トランジスタの小信号モデルは図 1 のように書ける。ただし、基板バイアス効果を見捨てる。また、相互コンダクタンスを  $g_m$ 、トランジスタの出力抵抗を  $r_o$ 、ゲート・ソース間電圧の小信号成分を  $v_{gs}$  とする。記号は凡例に従う。以下の問に答えよ。

- (1) 図 2 のように抵抗負荷  $R_D$  を付けたソース接地回路の小信号等価回路を示せ。さらに、電圧増幅率  $A_V$ 、入力抵抗  $R_{in}$ 、出力抵抗  $R_{out}$  を式で示せ。
- (2) 図 3 は、図 2 の抵抗負荷  $R_D$  の代わりに定電流源を付けたソース接地回路である。この回路の小信号等価回路を示せ。また、電圧増幅率  $A_V$  を式で示せ。
- (3) 定電流源の作り方として、図 4 のような回路を使うことが考えられる。この時の小信号等価回路を示せ。また、電圧増幅率  $A_V$  を式で示せ。
- (4) 図 5 のような回路を使って、図 4 における定電流源としての MOS にゲートバイアス  $V_b$  を与える。この回路では、 $I_{in}$  と同じ大きさの電流をいつでも  $I_{out}$  に流すことができる。このことに着目し、図 6 の差動増幅回路の差動ゲインを求めよ。
- (5) 図 7 のように差動増幅回路に容量で帰還を掛ける。この差動増幅回路の閉ループゲインを求めよ。

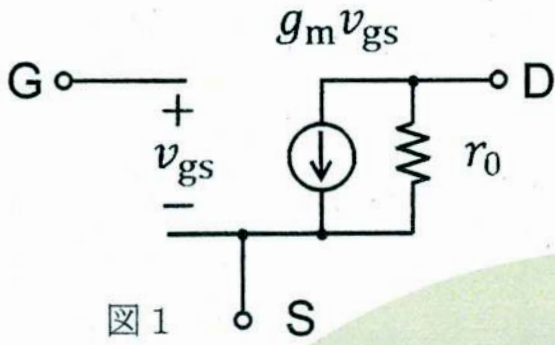


図1

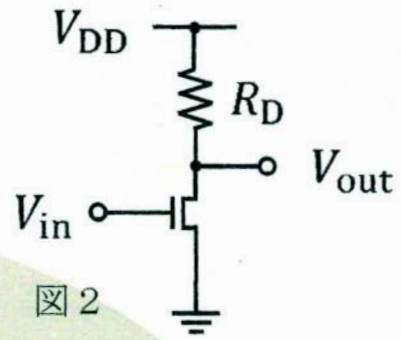


図2

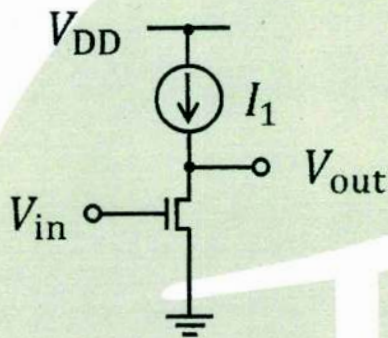


図3

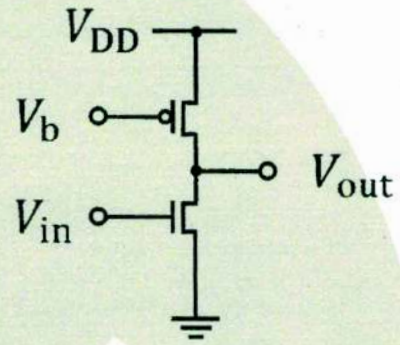


図4

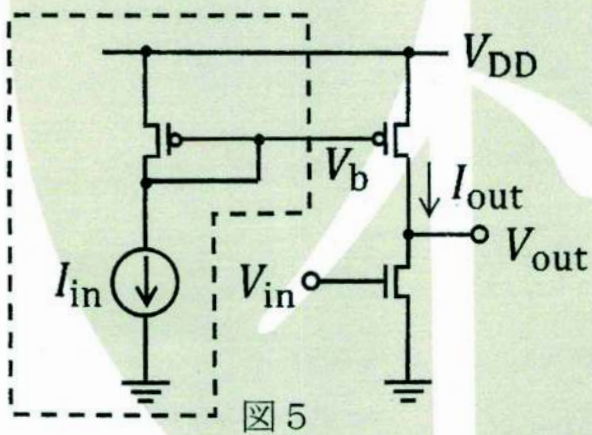


図5

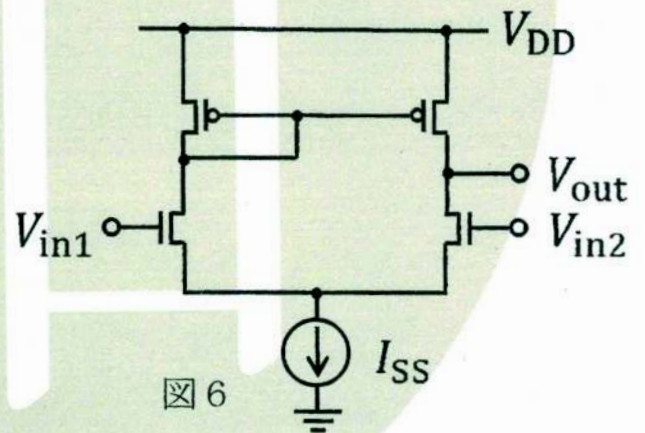


図6

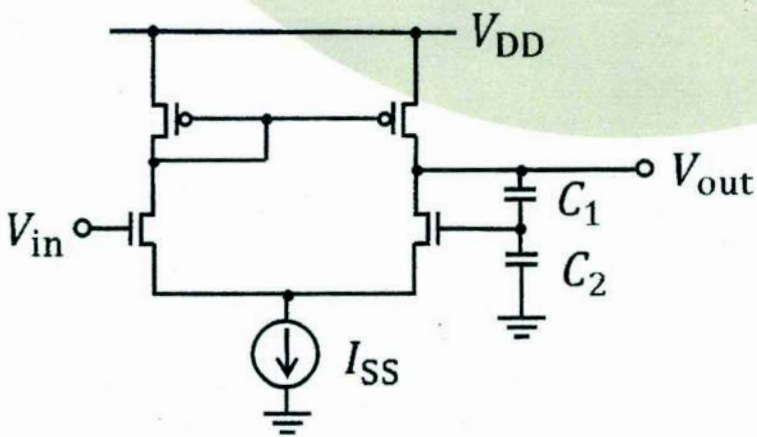
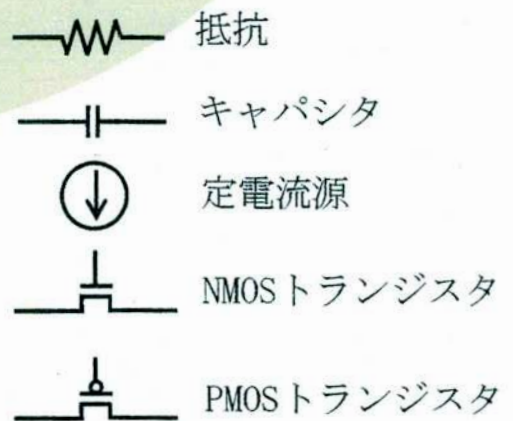


図7



凡例

## Problem 2

Because of the non-linear characteristics of MOS transistors, it is difficult to analyze their operation. Therefore, a minute range in the vicinity of the bias point is analyzed. This is referred to as the small-signal analysis method. Figure 1 shows the small-signal model of a short-channel MOS transistor. Here, the substrate bias effect is neglected, and let  $g_m$  be the transconductance,  $r_o$  be the output resistance, and  $v_{gs}$  be the small signal component of the gate-to-source voltage. Symbols in the figures can be found in the legend. Answer the following questions.

- (1) Draw the small-signal equivalent circuit of the common-source circuit with a load resistance  $R_D$  as shown in Fig. 2. In addition, express the voltage gain  $A_V$ , the input resistance  $R_{in}$ , and the output resistance  $R_{out}$ .
- (2) Figure 3 shows the common-source circuit after replacing  $R_D$  in Fig. 2 with a constant current source. Draw the small-signal equivalent circuit for it. In addition, find a formula for the voltage gain  $A_V$ .
- (3) A constant current source can be realized by a circuit shown in Fig. 4. Draw its small-signal equivalent circuit. In addition, find a formula for the voltage gain  $A_V$ .
- (4) The circuit shown in Fig. 5 is used to provide a gate bias  $V_b$  of the MOS transistor as a constant current source in Fig. 4. In this circuit, the current  $I_{out}$  is always equal to  $I_{in}$ . Taking this into account, show the differential gain of the differential amplifier circuit shown in Fig. 6.
- (5) As shown in Fig. 7, feedback is applied to the differential amplifier circuit by using the capacitors. Find the closed-loop gain of this differential amplifier circuit.

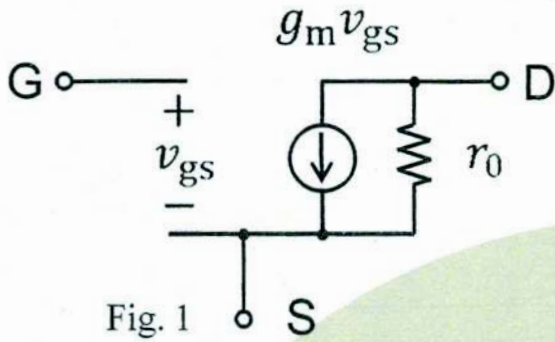


Fig. 1

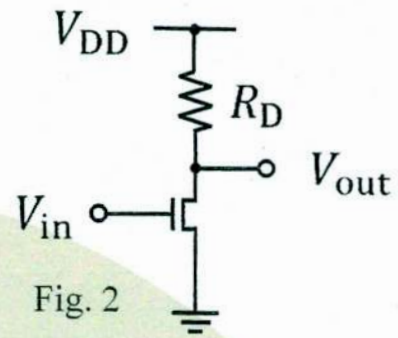


Fig. 2

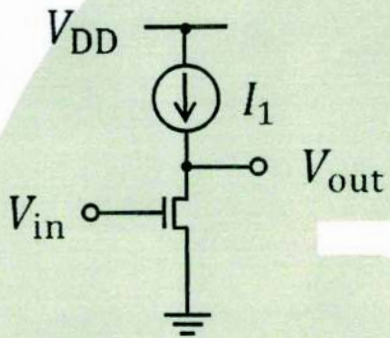


Fig. 3

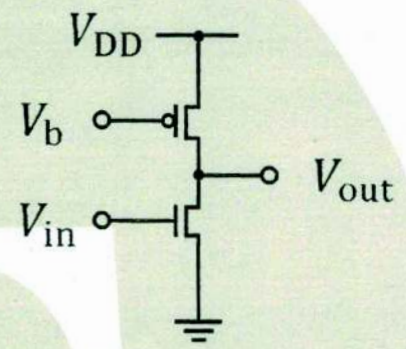


Fig. 4

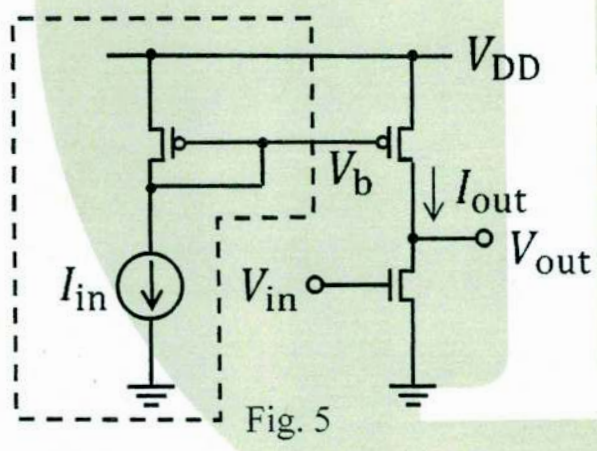


Fig. 5

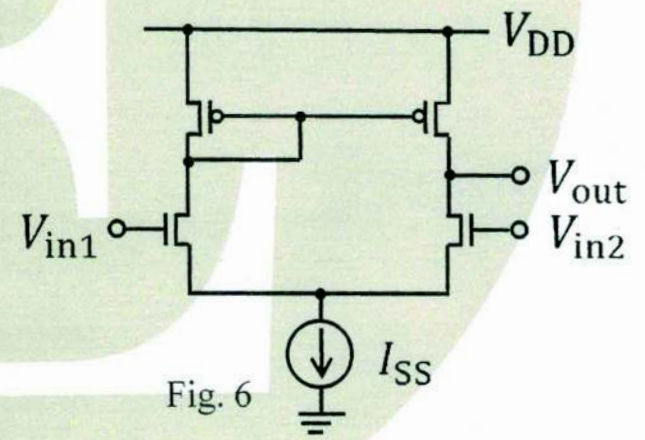


Fig. 6

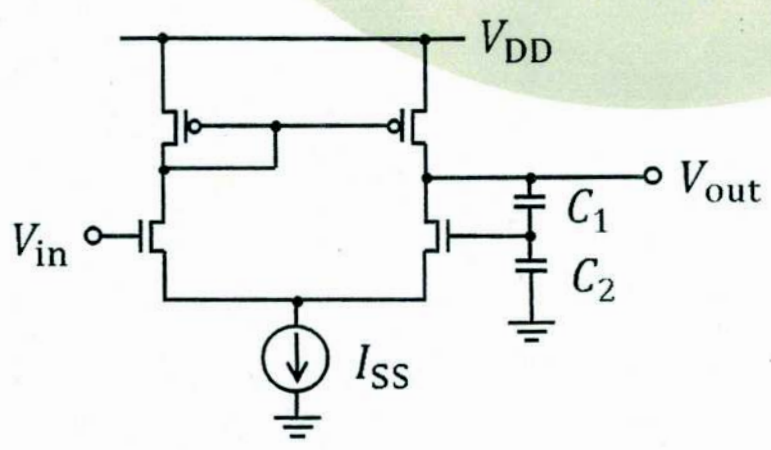
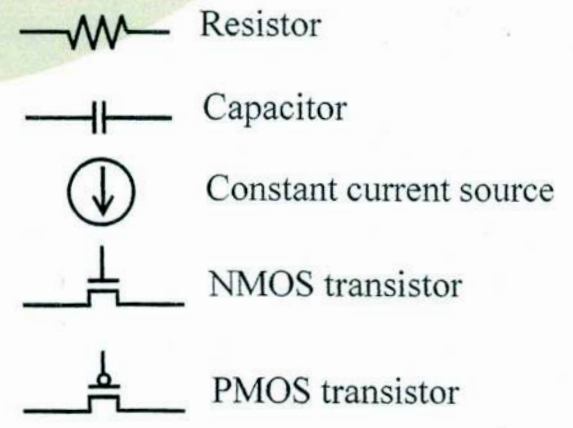


Fig. 7



Legend